

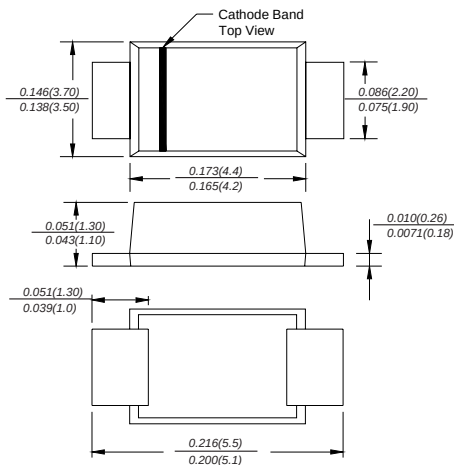


US3ABF THRU US3MBF

SURFACE MOUNT ULTRAFAST RECOVERY RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 3.0 Amperes

SMBF



Dimensions in inches and (millimeters)

FEATURES

- ◆ For surface mounted applications
- ◆ Low profile package
- ◆ Glass Passivated Chip Junction
- ◆ Easy to pick and place
- ◆ Superfast reverse recovery time
- ◆ Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

Case: JEDEC SMBF molded plastic body

Terminals: leads solderable per MIL-STD-750, Method 2026

Mounting Position: Any

Weight: 57mg/0.002oz

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	US3ABF	US3BBF	US3DBF	US3GBF	US3JBF	US3KBF	US3MBF	UNITS
Marking code		U3AB	U3BB	U3DB	U3GB	U3JB	U3KB	U3MB	
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at T _L =65°C	I _(AV)	3.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	100.0							Amps
Maximum instantaneous forward voltage at 3.0A	V _F	1.0			1.3	1.6			Volts
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =125°C	I _R	5.0 100.0							μA
Maximum reverse recovery time (NOTE 1)	t _{rr}	50				75			ns
Typical junction capacitance (NOTE 2)	C _J	75							pF
Typical thermal resistance (NOTE 3)	R _{θJA} R _{θJL}	55 16							°C/W
Operating junction and storage temperature range	T _J ,T _{STG}	-55 to +150							°C

Note: 1. Reverse recovery condition $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$

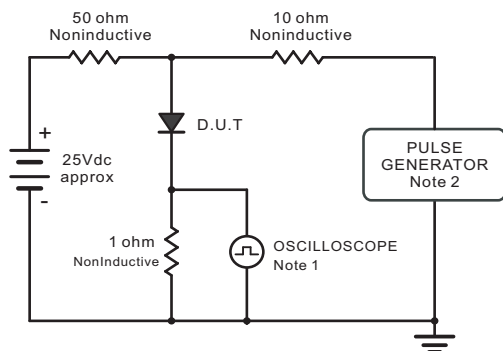
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

3. P.C.B. mounted with 0.5x0.5" (12.5x12.7mm) copper pad areas

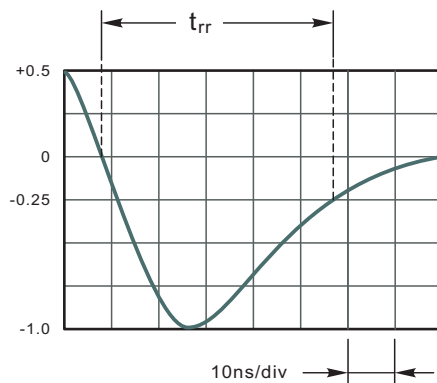


RATINGS AND CHARACTERISTIC CURVES US3ABF THRU US3MBF

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.
Input Impedance = 1megohm, 22pF.
2. Rises Time = 10ns, max.
Source Impedance = 50 ohms.



Set time Base for 10ns/div

Fig.2 Maximum Average Forward Current Rating

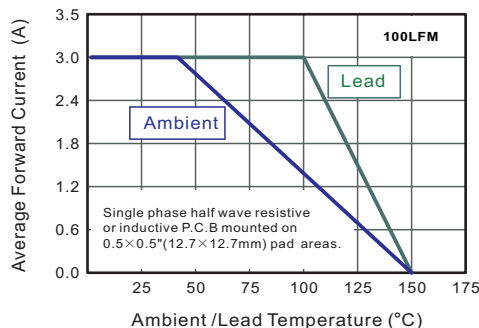


Fig.3 Typical Reverse Characteristics

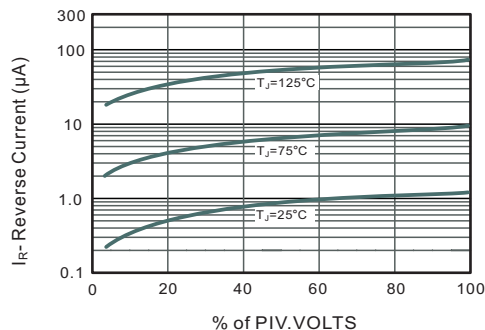


Fig.3 Typical Instantaneous Forward Characteristics

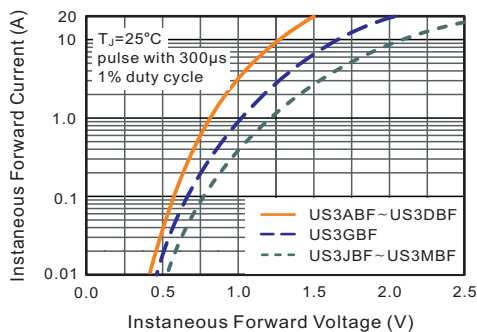
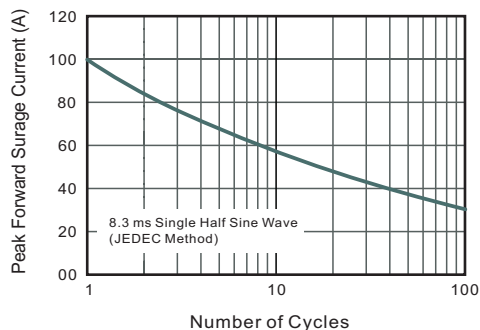


Fig.4 Maximum Non-Repetitive Peak Forward Surge Current



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!



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